



**THE DATASHEET OF
ZXM62P02E6TA**



Product Summary

BV_{DSS}	$R_{DS(ON)}$	I_D $T_A = +25^\circ C$
-20V	200m Ω @ $V_{GS} = -4.5V$	-2.3A

Description

This new generation of high density MOSFETs from Zetex utilizes a unique structure that combines the benefits of low on-resistance with fast switching speed. This makes them ideal for high efficiency, low voltage, power management applications.

Applications

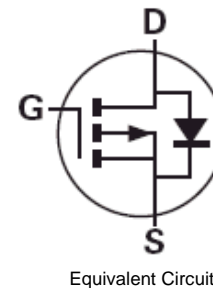
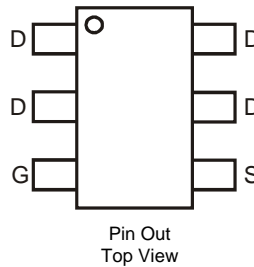
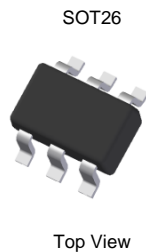
- DC - DC Converters
- Power Management Functions
- Disconnect Switches
- Motor Control

Features and Benefits

- Low On-resistance
- Fast Switching Speed
- Low Threshold
- Low Gate Drive
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Mechanical Data

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish - Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.018 grams (Approximate)

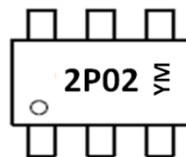


Ordering Information (Note 4)

Part Number	Reel Size (inch)	Tape Width (mm)	Quantity Per Reel
ZXM62P02E6TA	7	8	3,000
ZXM62P02E6TC	13	8	10,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



2P02 = Product Type Marking Code
 YM = Date Code Marking
 Y or \bar{Y} = Year (ex: C = 2015)
 M or \bar{M} = Month (ex: 9 = September)

Date Code Key

Year	2015	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025	2026
Code	C	D	E	F	G	H	I	J	K	L	M	N

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Absolute Maximum Ratings

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		V_{DSS}	-20	V	
Gate-Source Voltage		V_{GSS}	± 12	V	
Continuous Drain Current	$V_{GS} = -4.5V$	I_D	$T_A = +25^\circ C$ (Note 6)	-2.3	A
			$T_A = +70^\circ C$ (Note 6)	-1.7	
Pulsed Drain Current		(Note 7)	I_{DM}	-13	A
Continuous Source Current (Body Diode)		(Note 6)	I_S	-1.9	A
Pulsed Source Current (Body Diode)		(Note 7)	I_{SM}	-13	A
Power Dissipation at $T_A = +25^\circ C$		(Note 5)	P_D	1.1	W
Linear Derating Factor				8.8	
Power Dissipation at $T_A = +25^\circ C$		(Note 6)	P_D	1.7	W
Linear Derating Factor				13.7	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	$^\circ C$	

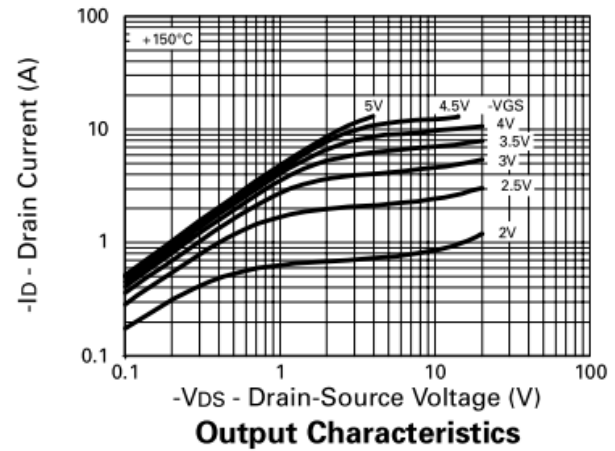
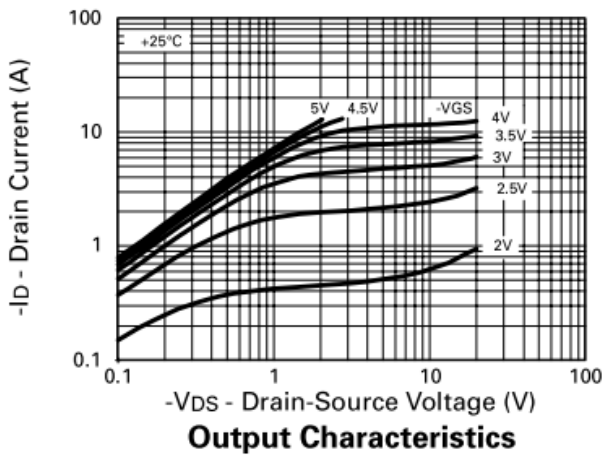
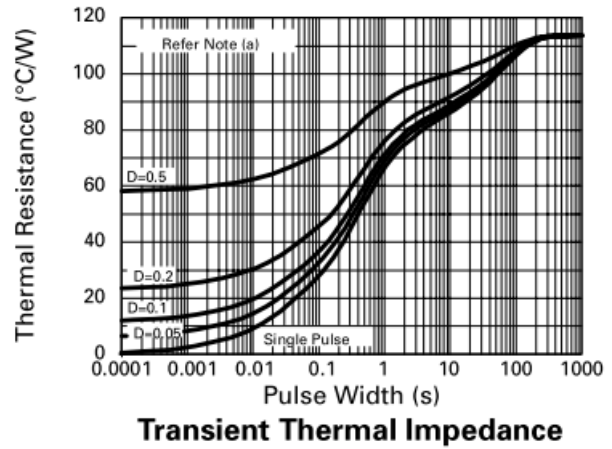
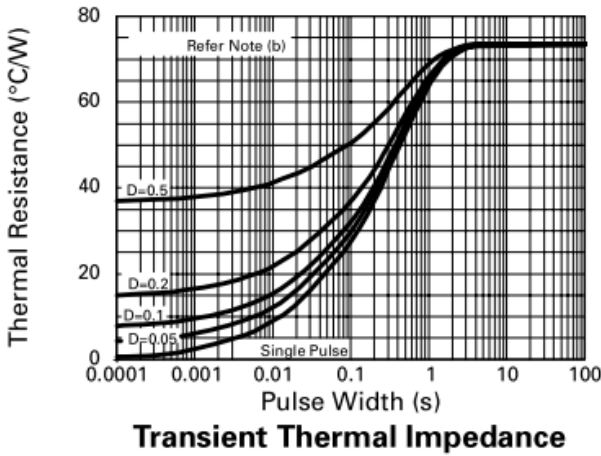
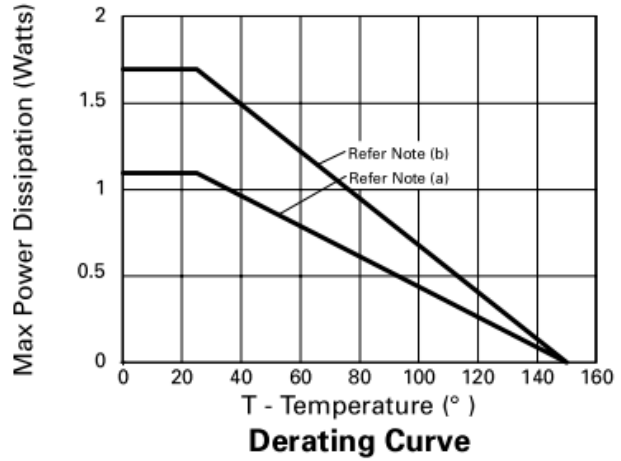
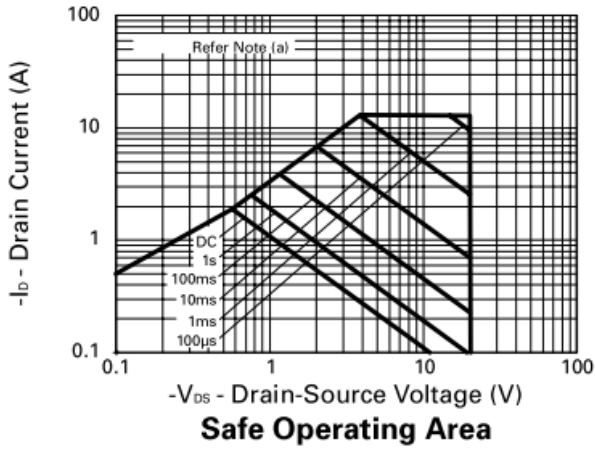
Thermal Resistance

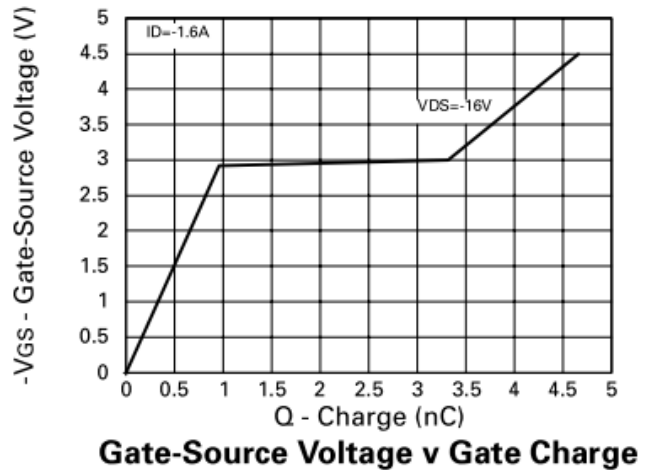
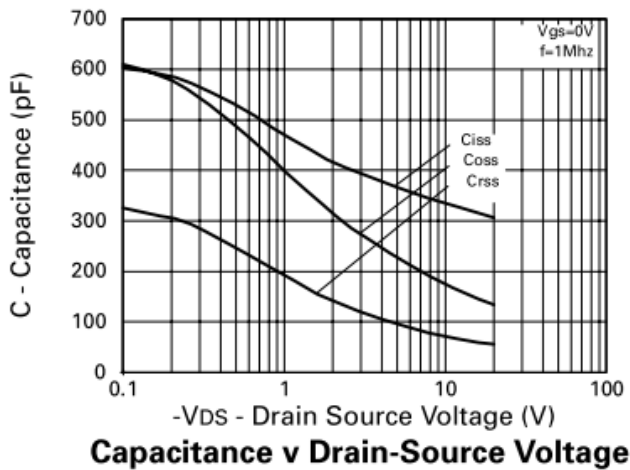
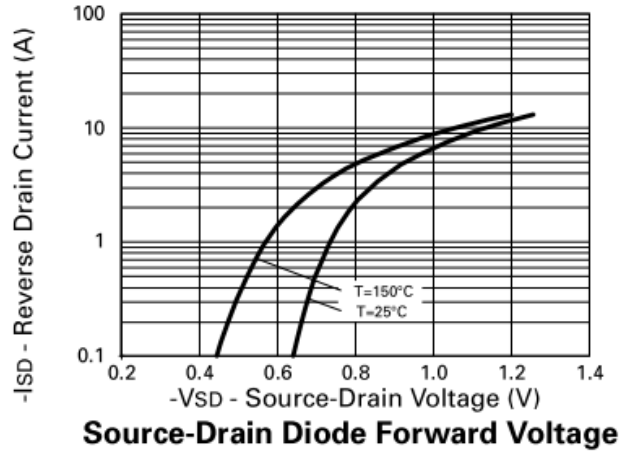
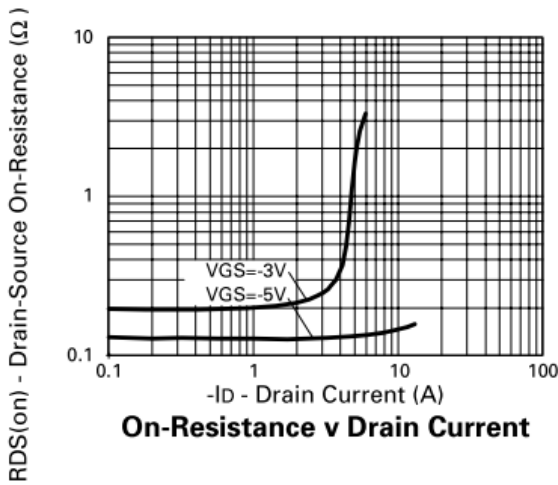
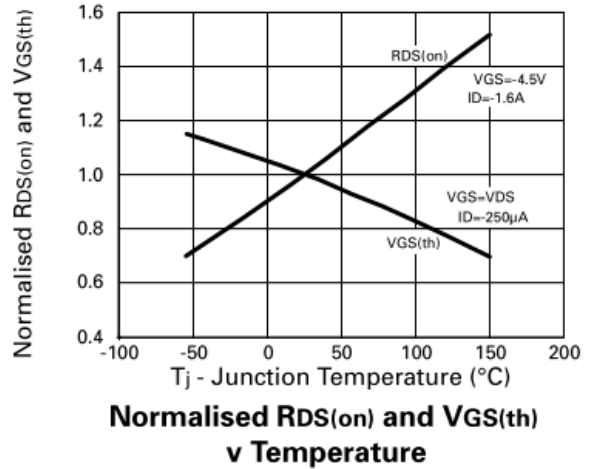
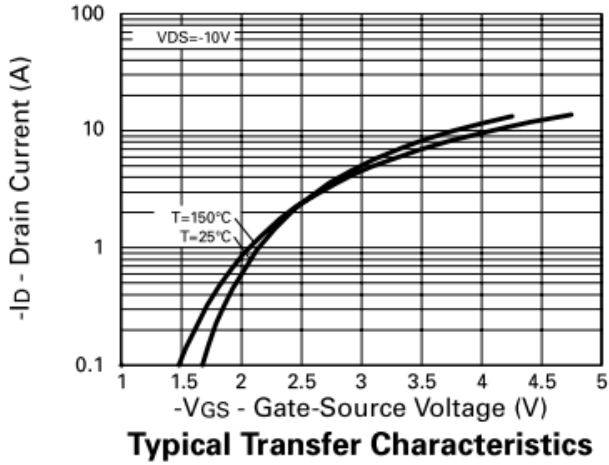
Characteristic		Symbol	Value	Unit
Junction to Ambient	(Note 5)	$R_{\theta JA}$	113	$^\circ C/W$
	(Note 6)		73	

Electrical Characteristics (@ $T_A = +25^\circ C$, unless otherwise stated.)

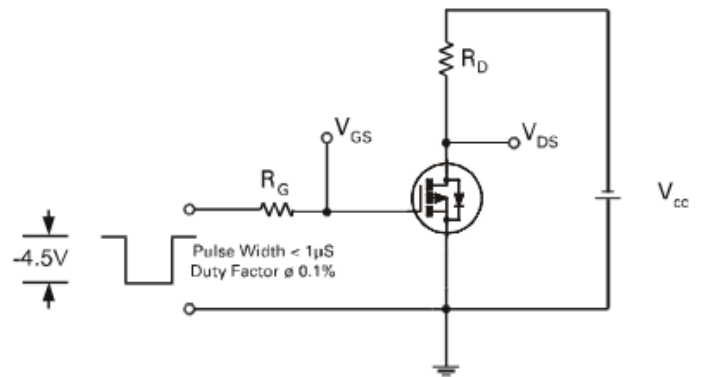
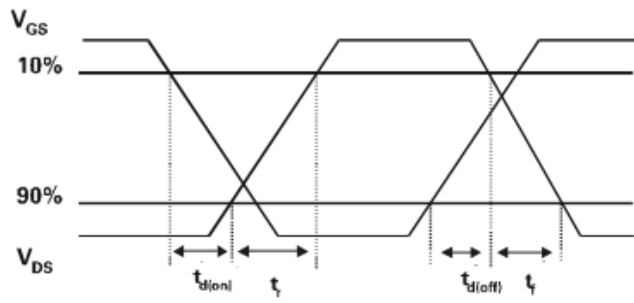
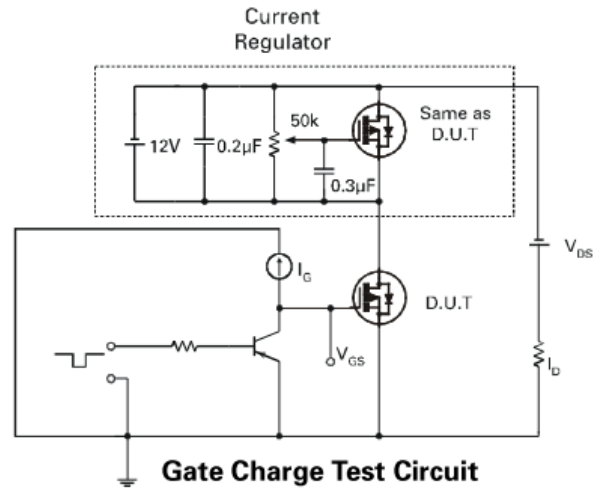
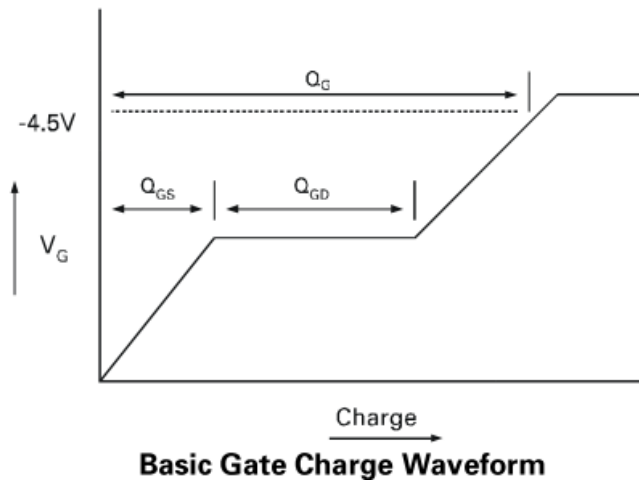
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
STATIC						
Drain-Source Breakdown Voltage	BV_{DSS}	-20	—	—	V	$I_D = -250\mu A, V_{GS} = 0V$
Zero Gate Voltage Drain Current	I_{DSS}	—	—	-1	μA	$V_{DS} = -20V, V_{GS} = 0V$
Gate-Source Leakage	I_{GSS}	—	—	± 100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$
Gate Threshold Voltage	$V_{GS(TH)}$	-0.7	—	—	V	$I_D = -250\mu A, V_{DS} = V_{GS}$
Static Drain-Source On-Resistance (Note 8)	$R_{DS(ON)}$	—	—	0.2	Ω	$V_{GS} = -4.5V, I_D = -1.6A$
				0.375		$V_{GS} = -2.7V, I_D = -0.8A$
Forward Transconductance (Note 10)	g_{fs}	1.5	—	—	S	$V_{DS} = -10V, I_D = -0.8A$
DYNAMIC (Note 10)						
Input Capacitance	C_{iss}	—	320	—	pF	$V_{DS} = -15V, V_{GS} = 0V$ $f = 1MHz$
Output Capacitance	C_{oss}	—	150	—	pF	
Reverse Transfer Capacitance	C_{rss}	—	75	—	pF	
SWITCHING (Notes 9 and 10)						
Total Gate Charge	Q_g	—	—	5.8	nC	$V_{DS} = -16V, V_{GS} = -4.5V$ $I_D = -1.6A$ (Refer to test circuit)
Gate-Source Charge	Q_{gs}	—	—	1.25	nC	
Gate-Drain Charge	Q_{gd}	—	—	2.8	nC	
Turn-On Delay Time	$t_{D(ON)}$	—	4.1	—	ns	$V_{DD} = -10V, I_D = -1.6A, R_G = 6\Omega,$ $R_D = 6.1\Omega$ (Refer to test circuit)
Turn-On Rise Time	t_R	—	15.4	—	ns	
Turn-Off Delay Time	$t_{D(OFF)}$	—	12.0	—	ns	
Turn-Off Fall Time	t_F	—	19.2	—	ns	
SOURCE-DRAIN DIODE						
Diode Forward Voltage (Note 8)	V_{SD}	—	—	-0.95	V	$T_J = +25^\circ C, I_S = -1.6A,$ $V_{GS} = 0V$
Reverse recovery time (Note 10)	t_{RR}	—	22.5	—	ns	$T_J = +25^\circ C, I_F = -1.6A,$
Reverse recovery charge (Note 10)	Q_{RR}	—	10.4	—	nC	$di/dt = 100A/\mu s$

- Notes:
5. For a device surface mounted on 25mm x 25mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions.
 6. For a device surface mounted on FR-4 PCB measured at $t \leq 5$ secs.
 7. Repetitive rating - pulse width limited by maximum junction temperature. Refer to Transient Thermal Impedance graph.
 8. Measured under pulsed conditions. Width= 300 μs ; duty cycle $\leq 2\%$.
 9. Switching characteristics are independent of operating junction temperatures.
 10. For design aid only, not subject to production testing.





Test Circuits

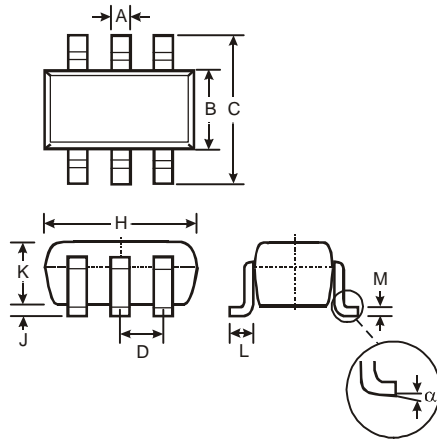


Switching Time Waveforms

Switching Time Test Circuit

Package Outline Dimensions

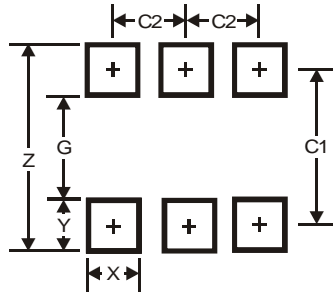
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT26			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
α	0°	8°	—
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

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